



### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	I <sub>D</sub> T <sub>A</sub> = +25°C
	0.99Ω @ V <sub>GS</sub> = 4.5V	0.5A
20V	1.2Ω @ V <sub>GS</sub> = 2.5V	0.45A
	1.8Ω @ V <sub>GS</sub> = 1.8V	0.37A
	2.4Ω @ V <sub>GS</sub> = 1.5V	0.32A

# **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Power-management functions
- Backlighting
- Load switches

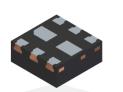
#### **Features**

- Low On-Resistance
- Low Input/Output Leakage •
- Fast Switching Speed
- **ESD** Protected Gate •
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) •
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

#### Mechanical Data

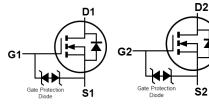
- Package: X2-DFN1010-6
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0015 grams (Approximate)

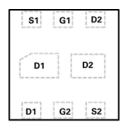




X2-DFN1010-6 (Type UXC)

**Bottom View** 





Equivalent Circuit

**Pinout Top View** 

# Ordering Information (Note 4)

Orderable Part Number	Package	Tape Width (mm)	Tape Pitch (mm)	Packing		
Orderable Fait Number	Fackage	rape width (mm)	Tape Filch (min)	Qty.	Carrier	
DMN2991UDR4-7	X2-DFN1010-6 (Type UXC)	8	4	5000	Tape & Reel	
DMN2991UDR4-7R	X2-DFN1010-6 (Type UXC)	8	4	5000	Tape & Reel	

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# Marking Information

	BQ = Product Type Marking Code YWX = Date Code Marking YWX YWX W = Week (ex: 4 = 2024) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)					
DMN2991UDR4-7	BQ YWX • <u>Pin 1</u>					
DMN2991UDR4-7R	XMA   BQ = Product Type Marking Code     YWX = Date Code Marking     Y = Year (ex: 4 = 2024)     W = Week (ex: a = Week 27; z Represents Week 52 and 53)     X = Internal Code (ex: U = Monday)					

#### Date Code Key

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	2	3	4	5	6	7	8	9	0	1	2	3
Week 1-26			27-52			53						
Code		A	A-Z			a-z			Z			
Internal Code	Sur	1	Mon		Tue	W	ed	Thu		Fri		Sat
Code	Т		U		V	V	V	Х		Y		Z



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	Vdss	20	V		
Gate-Source Voltage	Vgss	±8	V		
Continuous Drain Current (Note 5) V <sub>GS</sub> = 4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	ID	0.5 0.4	A
Maximum Continuous Body Diode Forward Current	ls	0.4	A		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	Ідм	1.4	A		

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.38	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	331	°C/W
Total Power Dissipation (Note 6)		PD	0.7	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	180	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)					•		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	_	_	V	Vgs = 0V, Ip = 10µA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μA	$V_{DS} = 16V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±10	μA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.4	—	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		_	0.5	0.99		Vgs = 4.5V, ID = 100mA	
Static Drain-Source On-Resistance	Pro/c+"	—	0.6	1.2	Ω	$V_{GS} = 2.5V, I_{D} = 50mA$	
Static Drain-Source On-Resistance	Rds(on)	—	0.7	1.8		$V_{GS} = 1.8V, I_{D} = 20mA$	
		_	0.9	2.4		$V_{GS} = 1.5V, I_D = 10mA$	
Diode Forward Voltage	Vsd	_	0.8	1.0	V	Vgs = 0V, Is = 150mA	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	14.6	—			
Output Capacitance	Coss	_	4.7	_	pF	V <sub>DS</sub> = 16V, V <sub>GS</sub> = 0V f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	3.2	_		1 - 1.00012	
Total Gate Charge	Qg	_	0.28	—			
Gate-Source Charge	Qgs	_	0.04	—	nC	$V_{GS} = 4.5V, V_{DS} = 10V$ ID = 250mA	
Gate-Drain Charge	Q <sub>gd</sub>	_	0.1	_	]		
Turn-On Delay Time	td(on)	_	7.1				
Turn-On Rise Time	t <sub>R</sub>	_	18	—		$V_{DD} = 10V, V_{GS} = 4.5V$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>		125		ns	$R_L = 47\Omega, R_G = 10\Omega$ ID = 200mA	
Turn-Off Fall Time	tF	_	56.9	_	]		

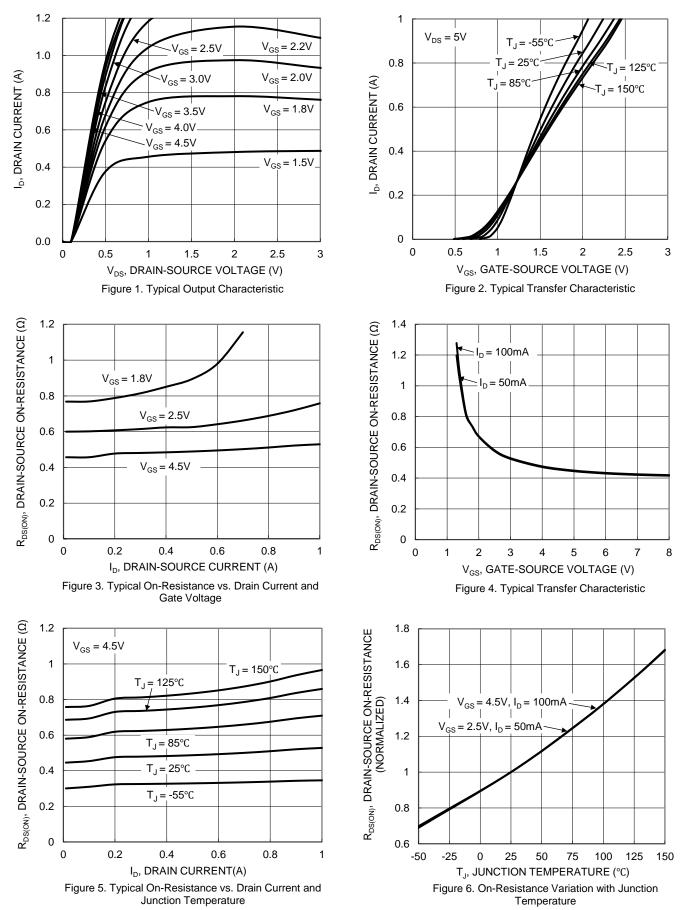
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.

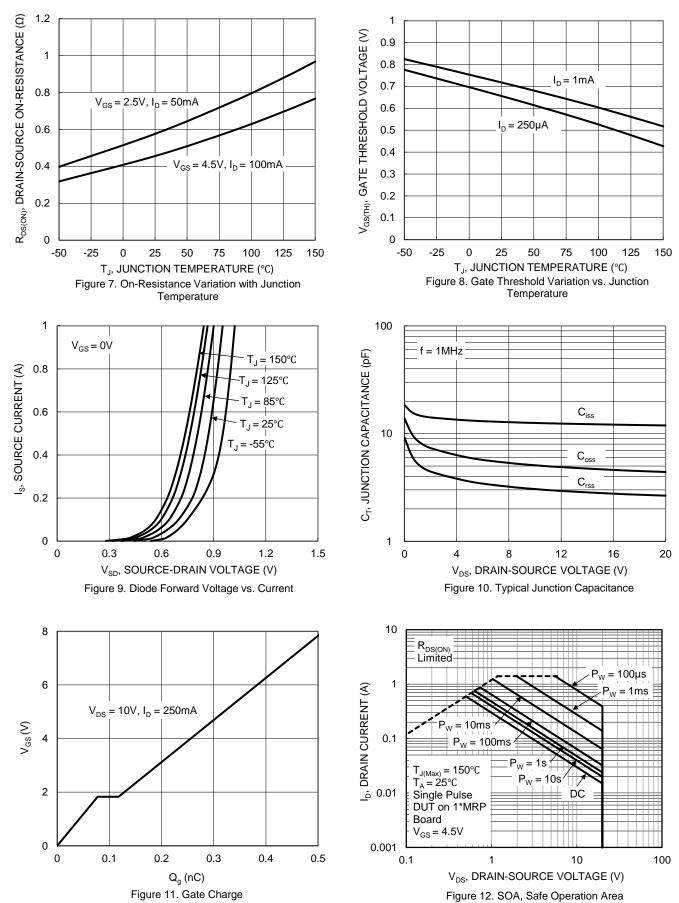


#### **DMN2991UDR4**



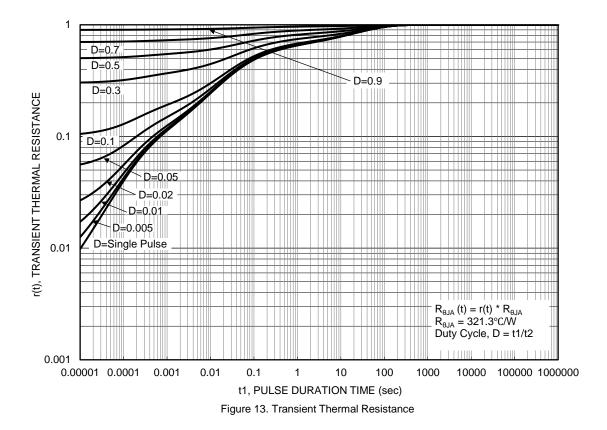


# **DMN2991UDR4**



DMN2991UDR4 Document number: DS44515 Rev. 5 - 2

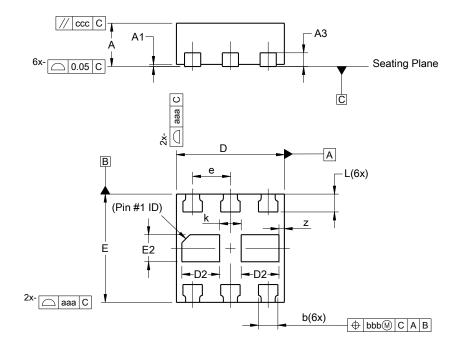






### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



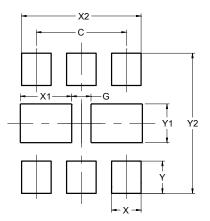
	X2-DFN1010-6								
Dim	(Type UXC) im Min Max Typ								
A	IVIIII	0.40	<b>Typ</b> 0.39						
A A1			0.39						
		0.05							
A3			0.127						
b	0.13	0.23	0.18						
D	0.95	1.05	1.00						
D2	0.30	0.40	0.35						
Е	0.95	1.05	1.00						
E2	0.20	0.30	0.25						
e	0.	350 BS	С						
_	0.115	0.215	0.165						
k			0.20						
z	0.02	0.08	0.05						
aaa	0.08								
bbb	0.07								
CCC	0.05								
All	Dimens	ions in	mm						

#### X2-DFN1010-6 (Type UXC)

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X2-DFN1010-6 (Type UXC)



Dimensions	Value (in mm)
С	0.700
G	0.300
Х	0.230
X1	0.450
X2	0.930
Y	0.250
Y1	0.300
Y2	1.085



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